# Supercurrent-phase relationship of a N b/InA s(2D E S)/N b Josephson junction in overlapping geom etry

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Superconductor/norm alconductor/superconductor (SN S) Josephson junctions with highly transparent interfaces are predicted to show signi cant deviations from sinusoidal supercurrent-phase relationships (CPR) at low temperatures. We investigate experim entally the CPR of a ballistic N b/InA s(2D E S)/N b junction in the temperature range from 1.3 K to 9 K using a modi ed R ifkin-D eaver m ethod. The CPR is obtained from the inductance of the phase-biased junction. Transport m easurem ents com plan ent the investigation. At low temperatures, substantial deviations of the CPR from conventional tunnel-junction behavior have been observed. A theoreticalm odel yielding good agreem ent to the data is presented.

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#### I. IN TRODUCTION

A fundamental item in the theoretical modeling of a Josephson junction is the dependency of the supercurrent  $I_{\rm S}$  owing through it on the phase di erence 'across the junction. Golubov, Kupriyanov and Il'ichev published a recent review on the subject.<sup>1</sup> As this relation is necessarily 2 -periodic and odd,<sup>2</sup> it can be expressed as the following Fourier series (with the critical current  $I_{\rm C}$ ):

$$I_{S}(') = I_{C} f(') = \prod_{n}^{X} I_{n} sin(n'):$$
 (1)

 $I_{\rm S}$  (') is known as (super-)current-phase relationship or CPR, the dimensionless term f (') as normalized CPR. For vanishing transparency (e.g. a tunnel junction), only  $I_1$  is relevant, reducing Eq. 1 to the well-known dc Josephson<sup>3</sup> equation

$$I_{S}(') = I_{1} \sin ' = I_{C} \sin ' :$$
 (2)

Junctions with direct (ie.non-tunnel) conductivity, such as the Nb/InAs(2DES)/Nb weak links used in this work, are predicted to show more complex behavior and a nonsinusoidal CPR due to higher order processes of charge transport such as multiple Andreev re ections.<sup>1,2,4</sup> Indications of a signi cant non-harm onic term in our junctions have been found in microw avem easurements.<sup>5,6</sup> W e are interested in experim ental access to the CPR as a way to test and im prove the theoreticalm odels describing our junctions, since the conduction mechanisms in these devices are still not fully understood. The measurements deliver not only the dependency f ('), but also  $I_{\rm C}$  , thus o ering an independent comparison to transport measurements.

II. THEORY

The rst extensive theoretical works concerning high transparency superconducting weak links were published by Kulik and Omel'yanchuk for a short quasiclassical point contact in the dirty  $\lim it'$  1 0 (with mean free path l and coherence length  $_0$ ) and for the clean lim  $it^4$ 0, predicting a CPR f (') changing from a sinusoidal 1 curve to a saw tooth shape for high transparencies and low tem peratures. These idealized model systems serve to understand the basic mechanisms leading to a deviation of the CPR from the well-known Josephson relation (Eq. 2), which we encounter also in complex real-world junctions, though m ixed with secondary processes. M echanically controlled break-junctions<sup>8</sup> com e closest to the assumptions of the theory of Kulik and Omelyanchuk. CPR measurements by a ux-detecting method in this system<sup>9</sup> agreed with the predicted changes in the position of the maximum and curve shape. In contrast to these systems, our SNS junctions exhibit a nite length, som e scattering of electrons in the 2DES, and an area of induced superconductivity around the electrodes caused by the proximity e ect. To take these properties into account and to describe the non-sinusoidalCPR in our experiments, we used the scattering matrix formalism  $^{10}$ to derive a form ula for the Josephson current through a double-barrier structure:<sup>11</sup>

$$\frac{\text{eIR}_{0}}{\text{k}_{B} \text{T}_{C}} = \frac{16\text{T}}{\text{T}_{C}} \frac{\text{K}^{1} \text{ K}^{1}}{\text{T}_{C}} \frac{\text{A}^{2} \beta_{12} \text{ f} \sin (\textbf{'})}{1 - 2\text{A}^{2} (\beta_{12} \text{ f} \cos(\textbf{'}) + \beta_{11} \text{ f}) + \text{A}^{4} \beta_{11}^{2} + S_{12}^{2} \text{ f}};$$
(3)

where R<sub>0</sub> = h=e<sup>2</sup> is the resistance quantum , A is the coefcient of the A ndreev rejection at the InA s(2D EG )/InA s interface and S<sub>ij</sub> are the elements of the scattering matrix for norm all rejection in a symmetric double barrier junction<sup>12</sup> S<sub>11</sub> = jrj+ jrjjtjp<sub>n</sub><sup>2</sup> = (1 + jrjp<sub>n</sub><sup>2</sup>), S<sub>12</sub> = jrj<sub>p<sub>n</sub> = (1 + jrjp<sub>n</sub><sup>2</sup>). Here jrj; jrj are the rejection and transmission probabilities of the left and right-hand barrier, p<sub>n</sub> = exp(ik<sub>F n</sub> a !m a=~v<sub>F n</sub>), where !m = (2m + 1) k<sub>B</sub> T are M atsubara frequencies, k<sub>F n</sub> and v<sub>F n</sub> are components norm al to the barriers of the wave vector and Ferm i velocity, respectively, of the n-th transverse m ode to the barriers and a is the distance between them . Follow ing the BTK approach,<sup>13</sup> the rejection and transmission coe cients can be written in the form</sub>

$$j_{2}f_{1}^{2} = 1 \qquad j_{2}f_{1}^{2} = \frac{1}{(1 (n=N)^{2})((n+1)^{2}=4 + Z^{2})}$$
(4)

where Z is the dimensionless potential barrier strength and  $= v_{F s} = v_{F n}$  is the Ferm i velocity m ism atch.

In order to calculate the Josephson current from Eq.3, one must determ ine the Andreev re ection coe cient A for the InAs(2DEG)/InAs interface. Since superconductivity is induced in InAs by the proximity e ect, the coe cient A may be written as  $^{14}$  A = iF = (1 + G), where F and G are G reen functions in the inversion layer of InAs. Due to the low electron density of the inversion layer the suppression of the pair potential in Nb can be neglected and F;G gan be expressed by the M dM illan equations<sup>15</sup> G =  $\frac{!= !^2 + 2}{!^2 + 2}$ , F =  $= \frac{12 + 2}{!^2 + 2}$ , and  $\frac{1}{2}$  +  $\frac{2}{2}$ , where <sub>B</sub> is a dimensionless = ~= (1 + <sub>B</sub> param eter characterizing the transparency between Nb and InAs,  $\sim = = k_B T_C$ ,  $! = ! = k_B T_C$ , is the superconducting energy gap of bulk Nb, and T<sub>C</sub> its critical tem perature. Both the critical tem perature and the energy gap of the Nb can be suppressed near the interface because of disorder<sup>16</sup> but ~ 0:6 rem ains constant.<sup>17</sup> Since  $T_C$  can be determined from temperature measurement, there are only two free thing parameters in the m odel, the carrier density  $n_s$  and B (we assume Z = 0, i.e. no real barrier). The Ferm i velocity  $v_F$  and Ferm i wave vector  $k_F$  are calculated for a given value of  $n_s$ . Since the norm all resistance depends on  $n_s$  as well, the ns obtained from the t can be veried comparing the theoretical and experim ental value of the resistance.

#### III. SAM PLE PREPARATION

The superconductor used in our SN S junctions is a N b thin lm, the norm al conductor is the two-dimensional

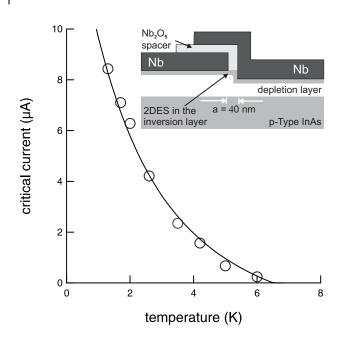


FIG.1: Tem perature dependence of the critical current. C incles are experim ental data, the solid line presents a tusing the m odel described in the text. The inset shows a schematic cross section of the Josephson junction.

electron system (2DES) that form s as naturally occurring inversion layer at the surface of bulk p-type InAs. The InAs surface is cleaned in situ using low energy Ar etching prior to the deposition of a 100 nm thick Nb lm by magnetron sputtering, yielding the highly transparent interfaces required to observe deviations from sinusoidal CPR. The structures are patterned using standard opticaland electron-beam lithography. We are using an overlapping sample geometry (see inset of Fig. 1), where we can set the electrode separation a with nm accuracy using anodic oxidation to grow the insulating N b<sub>2</sub>O 5 interlayer. At a typical electron density of  $n_s = 1.2$   $10^{12}$  cm<sup>2</sup> and m obility of  $10^4$  cm<sup>2</sup>/Vs, the mean free path of 1= 240 nm is much longer than the electrode separation a = 40 nm. From the dependence of the critical current on the channel length, we estim ate the coherence length 145 nm at 1.8 K. Thus we have a ballistic (a 1) N superconducting weak link in the short lim it (a M ore details have been published by Chrestin et al.<sup>18</sup>

The use of the native 2D ES on p-type InAs is not without di culties, as it forms on every surface of the crystal. Thus it o ers parallel conduction paths, resulting in signi cant bypass currents around the junction, which reduce the norm al resistance  $R_{\rm N}$ .

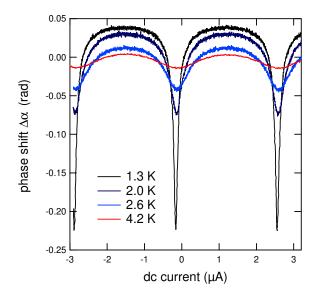


FIG.2: M easured phase shift at various tem peratures.

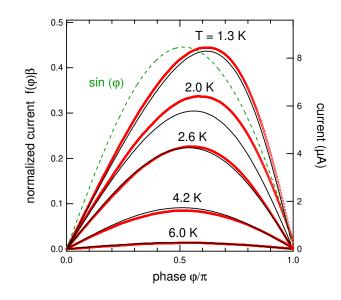


FIG.3:CPR (red) at tem peratures between 1.3 K and 6.0 K, reconstructed from the data in Fig.2. The solid lines are a t according to the model described in the text. For com parison, a pure sine curve is included.

## IV. CPR MEASUREMENT TECHNIQUE

The CPR of the Josephson junction is determined by an inductive rf frequency method requiring no galvanic contacts to the sample, thus reducing noise. This technique is based on the work of R ifkin and Deaver.<sup>19</sup> The junction to be investigated is incorporated into a superconducting loop. This loop form san rfSQUD of inductance L, which is coupled inductively to a high quality tank circuit in resonance. The phase di erence ' across the junction can be biased by an external magnetic ux e via a dc current Idc. Changes in the impedance of the coupled system are measured and can be used to reconstruct the CPR. Further details are given in Ref. 1. Thism ethod requires low critical currents I<sub>c</sub> of the junction and low inductances L of the SQUID washer, as the SQUD enters the hysteretic regime when  $f^0(') > 1$ , where = 2  $LI_c = 0$  is the normalized critical current and  $f^0(') = df(')=d'$ . In the hysteretic mode the internal magnetic ux as a function of the external one becomes multivalued, preventing us to reconstruct the CPR in the complete phase range (0;2). The challenge is to reduce I<sub>c</sub> and L while maintaining excellent interface transparency, large  $I_C R_N$  products, and su cient coupling to the tank circuit. W eachieve this by reducing the geometric dimensions of the junction and the loop and by complex washer designs. The presented junction is connected to six SQUID washers in parallel with an integrated ux transform er, for an inductance of L = 17 pHand optim ized coupling to the tank circuit. A similar transform er is described and depicted in Ref. 1.

# V. RESULTS

The experiments are performed on an overlapping Josephson junction of width w = 1 m and electrode separation a = 40 nm. Transport measurements at 1.8 K result in  $I_{\rm C}$  = 3:8 A,  $R_{\rm N}$  = 58 ,  $I_{\rm C}\,R_{\rm N}$  = 220 V, and show clearly developed subharmonic gap structures (SG S) in the di erential resistance of the junction. This indicates high interface quality and transparency of the junctions.

Figure 2 shows the recorded phase shift in the tank circuit as a function of the applied quasi-dc current  $I_{dc}$  ramping the external ux  $_{e}$  through the SQUID bop. This signal was averaged for 20 periods to reduce noise and then used to reconstruct the CPR depicted in Fig.3. For decreasing temperatures, gradual deviation of the CPR from conventional sinusoidal behavior towards a saw tooth-shaped curve is observed. The position of m axim um current is shifted to 0:63 at 1.3 K. At the same time, the critical current increases substantially, so that at some temperature the SQUID enters the hysteretic regime as  $f^{0}(')$  approaches unity. In that case we are no longer able to reconstruct the CPR at lower temperatures.

The  $I_{\rm C}$  T dependence was tted by the model described above using the least squares method with two tting parameters  $n_{\rm S}$  and  $_{\rm B}$ . The other parameters used in the calculation were determined independently as critical temperature  $T_{\rm C}$  = 6:5 K, width w = 1:0 m, electrode separation a = 40 nm, interface parameter Z = 0, and Ferm i velocity mism atch = 0:93. The tting procedure yields the parameters  $n_{\rm s}$  = 3:75  $10^{12}$  cm  $^2$  and  $_{\rm B}$  = 2:4 and good agreement between theoretical and

experimental data (see Figs. 1 and 3). Note that the model ts the current-phase characteristic quite well for the param eters determ ined from the tem perature dependence of the critical current. Only the curve taken at Т 2:0 K exhibits some deviation from the theoreticalone. However, the tem perature dependence of  $I_{\rm C}$  (T) is rather steep at low temperatures and a sm all di erence between the tem perature of the therm om eter and the sample could be responsible. From the above param eters we calculate the junction resistance of  $R_N = 83$  . Transport measurements yield a slightly lower value of 58 , but as we measure a parallel connection between substrate and junction, a higher junction resistance is to be expected. A realistic substrate resistance of 180 produces the measured value of 58 . The interface param eters indicate a highly transparent junction. The assumed carrier density is about three times the result  $10^{12}$  cm  $^2$  from Shubnikov-de Haasmeasure $n_s = 1:2$ m ents on comparable samples. Nevertheless,  $n_s$  as determ ined from our model is consistent with the smaller experimental value of the junction resistance. A possible explanation for both e ects is an e ective widening of the contact due to the proxim ity e ect in the surrounding 2DES.

#### VI. CONCLUSION

We have successfully measured the current-phase relationship (CPR) of a Nb/InAs(2DES)/Nb Josephson

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junction in dependence of tem perature. At low tem peratures, substantial deviations of the CPR from a sinusoidal behavior towards a saw tooth shape are observed. This is in qualitative agreem ent with predictions of the K ulik-Om elyanchuk theory for highly transparent SN S junctions and the m easurem ents on Josephson eld effect transistors presented in Ref. 11. A m odel yielding good quantitative agreem ent to the results is presented. T ransport m easurem ents support the results gained by phase sensitive m easurem ents.

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